

SS2PH9 & SS2PH10

Vishay General Semiconductor

# **High-Voltage Surface Mount Schottky Barrier Rectifiers**

High Barrier Technology for Improved High Temperature Performance

## FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Low forward voltage drop, low power (e3) losses RoHS
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

## **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	SS2PH9 SS2PH10		UNIT	
Device marking code		29 210			
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	V <sub>RRM</sub> 90 100		V	
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	2.0		А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50		A	
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.5 A, L = 10 mH	E <sub>AS</sub>	11.25		mJ	
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175		°C	

DO-220AA (SMP)

eSMP<sup>™</sup> Series

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2.0 A			
V <sub>RRM</sub>	90 V, 100 V			
I <sub>FSM</sub>	50 A			
E <sub>AS</sub>	11.25 mJ			
$V_F$ at $I_F$ = 1.0 A	0.62 V			
I <sub>R</sub> max.	1.0 μA			
T <sub>J</sub> max.	175 °C			

#### Document Number: 84682 Revision: 19-May-08



COMPLIANT



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 2.0 A I <sub>F</sub> = 2.0 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.77 0.62	0.80 0.66	V
Maximum reverse current at rated $\mathrm{V_R}^{(2)}$		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	0.1 60	1.0 500	μΑ
Typical junction capacitance	4.0 V, 1 MHz		CJ	65	-	pF

#### Notes:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \degree C$ unless otherwise noted)						
PARAMETER	SYMBOL SS2PH9 SS2PH10		UNIT			
Typical thermal resistance <sup>(1)</sup>	R <sub>θJA</sub> R <sub>θJL</sub> R <sub>θJC</sub>	110 15 25		°C/W		

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 15 x 15 mm copper pad areas.  $R_{0JL}$  is measured at the terminal of cathode band.  $R_{0JC}$  is measured at the top center of the body

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS2PH9-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel	
SS2PH9-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel	
SS2PH9HE3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel	
SS2PH9HE3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel	

#### Note:

(1) Automotive grade AEC Q101 qualified

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

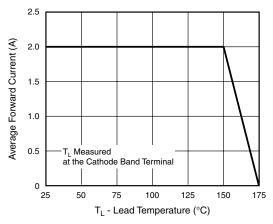


Figure 1. Forward Current Derating Curve

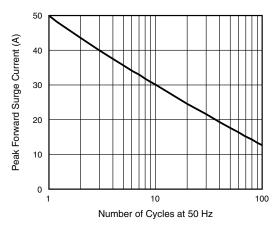


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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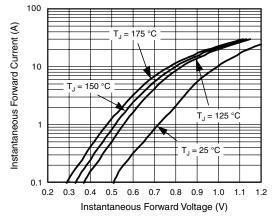


Figure 3. Typical Instantaneous Forward Characteristics

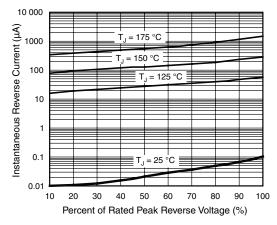


Figure 4. Typical Reverse Leakage Characteristics

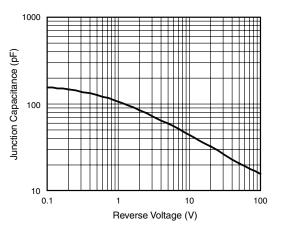


Figure 5. Typical Junction Capacitance

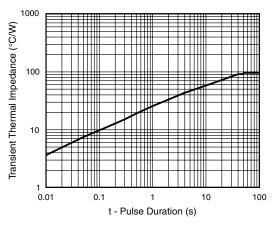
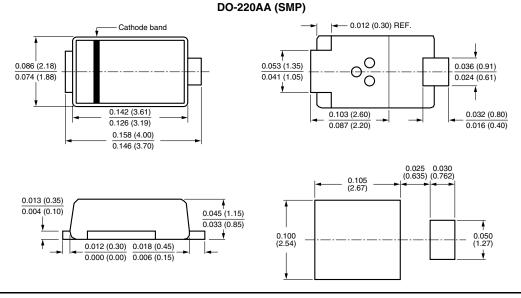


Figure 6. Typical Transient Thermal Impedance

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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